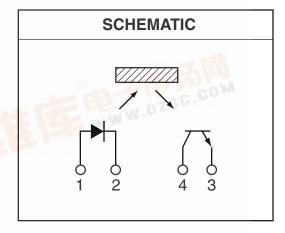


QRB1113 QRB1114

PACKAGE DIMENSIONS 0.420 (10.67) 0.328 (8.33) 0.150 (3.81) NOM PIN PIN 2 Ш 0.226 (5.74) 0.373 (9.47) 0.703 (17.86) PIN 3 □ PIN 4 0.020 (0.51) 0.150 (3.81) 4X MIN - 0.210 (5.33) -0.603 (15.32)-REFLECTIVE SURFACE 0.300 (7.62) PIN1 ANODE PIN2 CATHODE PIN3 EMITTER PIN4 COLLECTOR NOTES: 1. Dimensions for all drawings are in inches (mm). 2. Tolerance of ± .010 (.25) on all non-nominal dimensions unless otherwise specified.





DESCRIPTION

The QRB1113/1114 consists of an infrared emitting diode and an NPN silicon phototransistor mounted side by side on a converging optical axis in a black plastic housing. The phototransistor responds to radiation from the emitting diode only when a reflective object passes within its field of view. The area of the optimum response approximates a circle .200" in diameter.

FEATURES

- No contact surface sensing
- Phototransistor output
- Focused for sensing specular reflection
- Daylight filter on photosensor
- Dust cover





QRB1113 QRB1114

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)			
Parameter	Symbol	Rating	Units
Operating Temperature	T _{OPR}	-40 to +85	°C
Storage Temperature	T _{STG}	-40 to +85	°C
Soldering Temperature (Iron)(2,3,4)	T _{SOL-I}	240 for 5 sec	°C
Soldering Temperature (Flow) ^(2,3)	T _{SOL-F}	260 for 10 sec	°C
EMITTER			
Continuous Forward Current	I _F	50	mA
Reverse Voltage	V _R	5	V
Power Dissipation ⁽¹⁾	P _D	100	mW
SENSOR			
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Collector Voltage	V _{ECO}	4.5	V
Collector Current		20	mA
Power Dissipation ⁽¹⁾	P _D	100	mW

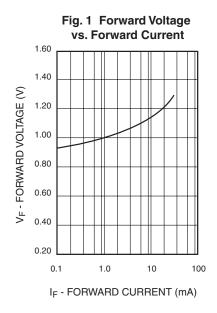
NOTES

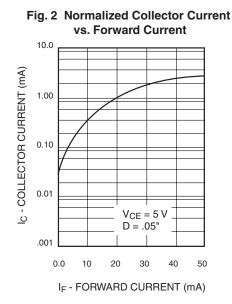
- 1. Derate power dissipation linearly 1.67 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6mm) minimum from housing.
- 5. D is the distance from the assembly face to the reflective surface.
- Measured using an Eastman Kodak neutral test card with 90% diffused reflecting surface.
 Cross talk is the photo current measured with current to the input diode and no reflecting surface.
- **ELECTRICAL/OPTICAL CHARACTERISTICS** (T_A = 25°C) **Parameter Test Conditions Symbol Units** Min. Max. Typ. **EMITTER** Forward Voltage $I_F = 40 \text{ mA}$ V_{F} 1.7 $V_{B} = 5.0 \text{ V}$ Reverse Current I_R 100 μΑ $I_F = 20 \text{ mA}$ Peak Emission Wavelength λ_{PF} 940 nm **SENSOR** $I_C = 1 \text{ mA}$ BV_{CFO} Collector-Emitter Breakdown Voltage 30 ٧ BV_{ECO} Emitter-Collector Breakdown Voltage $I_E = 0.1 \text{ mA}$ 5 V $V_{CE} = 10 \text{ V}, I_F = 0 \text{ mA}$ Collector-Emitter Dark Current I_{CFO} 100 nΑ COUPLED On-state Collector Current $I_F = 40 \text{ mA}, V_{CE} = 5 \text{ V}$ QRB1113 0.20 mΑ I_{C(ON)} $D = .150^{(5,6)}$ QRB1114 0.60 Collector-Emitter $I_F = 20 \text{ mA}, I_C = 0.5 \text{ mA}$ V_{CE (SAT)} V 0.4 Saturation Voltage $V_{CE} = 5 \text{ V}, R_{L} = 100 \text{ V}$ Rise Time t_r 8 μs $I_{C(ON)} = 5 \text{ mA}$ Fall Time t_f 8 Cross Talk $I_F = 40 \text{ mA}, V_{CE} = 5 V^{(7)}$ I_{CX} 1.00 μΑ

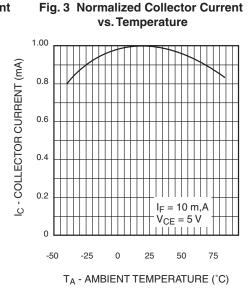


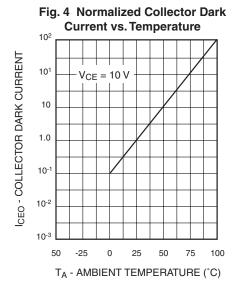
QRB1113 QRB1114

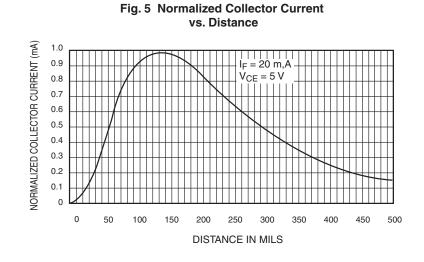
TYPICAL PERFORMANCE CURVES













QRB1113 QRB1114

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.